

NPN SILICON EPITAXIAL TRANSISTOR  
MP-3

## DESCRIPTION

2SD1584-Z is designed for Audio Frequency Amplifier and Switching, especially in Hybrid Integrated Circuits.

## FEATURES

- High  $h_{FE}$ :  $h_{FE} = 800$  to  $3\ 200$
- Low  $V_{CE(sat)}$ :  $V_{CE(sat)} = 0.25$  V TYP.

## QUALITY GRADE

Standard

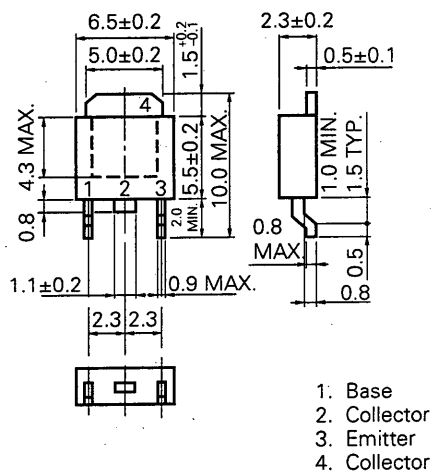
Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ( $T_a = 25\ ^\circ\text{C}$ )

Collector to Base Voltage	$V_{CBO}$	60	V
Collector to Emitter Voltage	$V_{CEO}$	60	V
Emitter to Base Voltage	$V_{EBO}$	7	V
Collector Current (DC)	$I_c$	3	A
Collector Current (Pulse)*	$I_c$	5	A
Total Power Dissipation ( $T_a = 25\ ^\circ\text{C}$ )**	$P_T$	2.0	W
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

\*  $PW \leq 10$  ms, Duty Cycle  $\leq 50$  %

\*\* When mounted on ceramic substrate of  $7.5\ \text{cm}^2 \times 0.7\ \text{mm}$

PACKAGE DIMENSIONS  
(in millimeters)

**ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)**

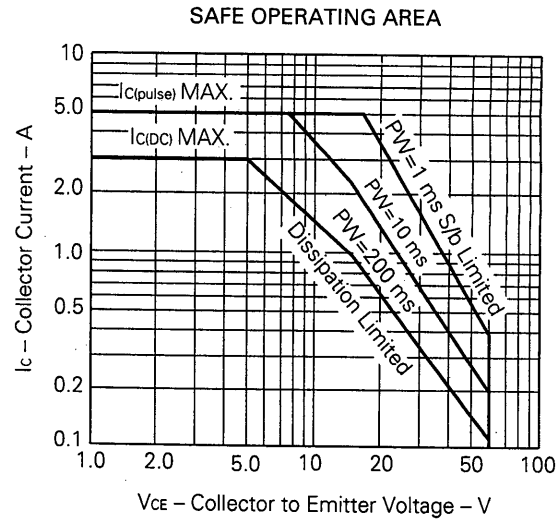
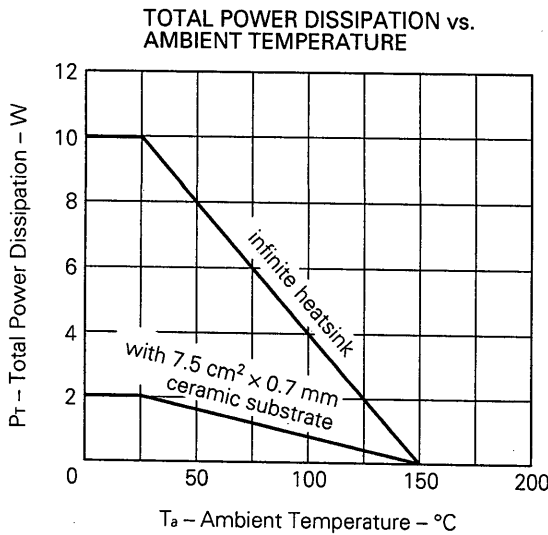
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I <sub>cbo</sub>			10	μA	V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0
Emitter Cutoff Current	I <sub>EBO</sub>			10	μA	V <sub>EB</sub> = 5.0 V, I <sub>C</sub> = 0
DC Current Gain	h <sub>FE1</sub> *	600	1 650			V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 50 mA
DC Current Gain	h <sub>FE2</sub> *	800	1 800	3 200		V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 500 mA
DC Current Gain	h <sub>FE3</sub> *	500	1 400			V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 3.0 A
Collector Saturation Voltage	V <sub>CE(sat)</sub> *		0.25	0.5	V	I <sub>C</sub> = 2.0 A, I <sub>B</sub> = 20 mA
Base Saturation Voltage	V <sub>BE(sat)</sub> *		0.8	1.2	V	I <sub>C</sub> = 2.0 A, I <sub>B</sub> = 20 mA
Gain Bandwidth Product	f <sub>T</sub>	50	120		MHz	V <sub>CE</sub> = 5.0 V, I <sub>E</sub> = -100 mA
Output Capacitance	C <sub>ob</sub>		20		pF	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz
Turn-on Time	t <sub>on</sub>		0.9		μs	I <sub>C</sub> = 2.0 A, R <sub>L</sub> = 5 Ω I <sub>B1</sub> = -I <sub>B2</sub> = 20 mA V <sub>CC</sub> = 10 V
Storage Time	t <sub>stg</sub>		2.6		μs	
Fall Time	t <sub>f</sub>		1.0		μs	

\* Pulsed: PW ≤ 350 μs, Duty Cycle ≤ 2 %

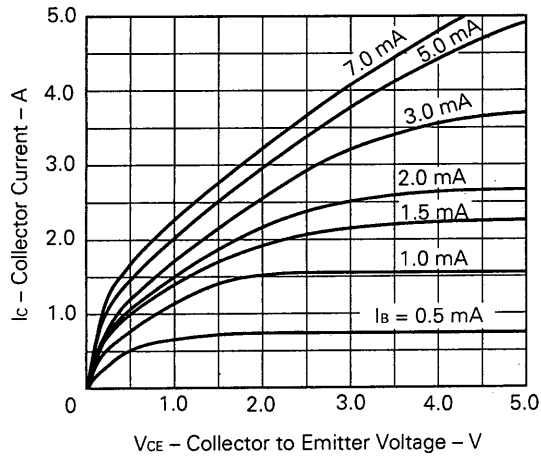
**h<sub>FE</sub> Classification**

MARKING	M	L	K
h <sub>FE2</sub>	800 to 1 600	1 000 to 2 000	1 600 to 3 200

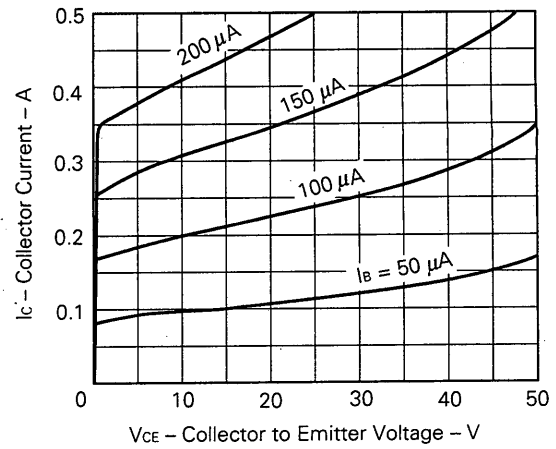
**TYPICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)**



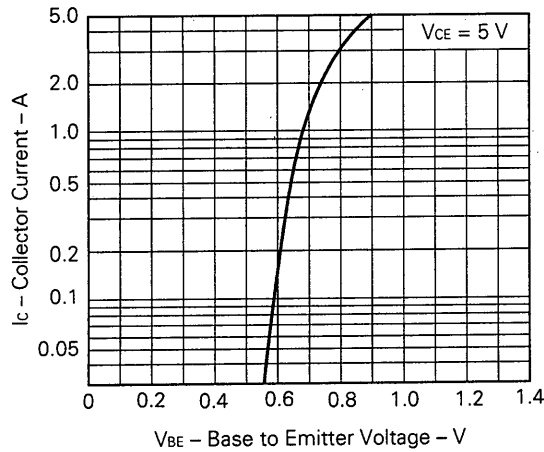
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



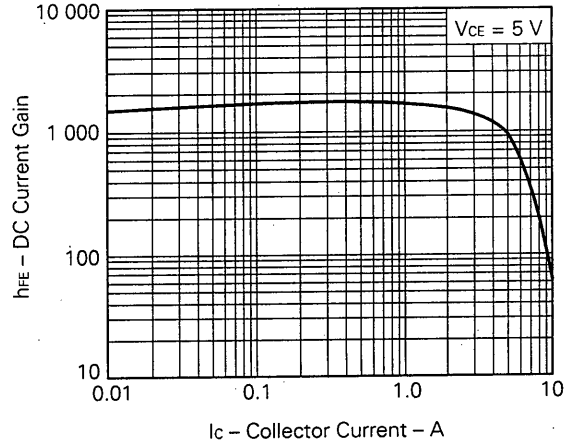
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



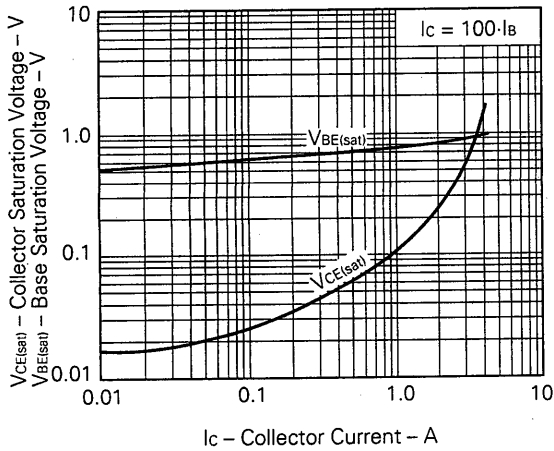
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



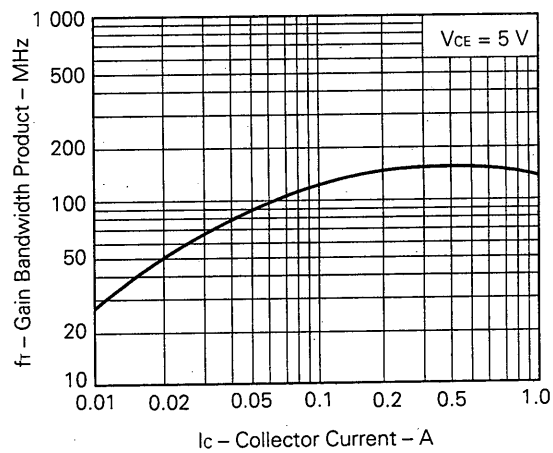
DC CURRENT GAIN vs. COLLECTOR CURRENT



BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



**Reference**

Application note name	No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Design of Push-Pull Type Switching Regulators (Basic)	TEB-1002
Design of Push-Pull Type Switching Regulators (Applications)	TEB-1003
Optimum Base Drive Conditions of Switching Power Transistors	TEB-1014

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

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